MBRA210ET3

Surface Mount **Schottky Power Rectifier**

SMA Power Surface Mount Package

This device employs the Schottky Barrier principle in a metal-to-silicon power rectifier. Features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies; free wheeling diodes and polarity protection diodes. Typical applications are AC/DC and DC-DC converters, reverse battery protection, and "Oring" of multiple supply voltages and any other application where performance and size are critical.

Features

- Low I_R, Extends Battery Life
- 1st in the Market Place with a 10 V_R Schottky Rectifier
- Compact Package with J-Bend Leads Ideal for Automated Handling
- Highly Stable Oxide Passivated Junction
- Guardring for Over-Voltage Protection
- Optimized for Low Leakage Current
- Pb-Free Package is Available

Mechanical Characteristics

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 70 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead
- ESD Ratings:

Machine Model = CHuman Body Model = 3B



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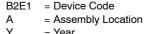
SCHOTTKY BARRIER RECTIFIER 2 AMPERES 10 VOLTS



CASE 403D PLASTIC

MARKING DIAGRAM





= Year

- ww = Work Week
- = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]		
MBRA210ET3	SMA	5000/Tape & Reel		
MBRA210ET3G	SMA (Pb-Free)	5000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	10	V
Average Rectified Forward Current (At Rated V_R , T_C = 125°C)	Ι _Ο	2.0	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	100	A
Storage/Operating Case Temperature	T _{stg} , T _C	-65 to +150	°C
Operating Junction Temperature	TJ	-65 to +150	°C
Voltage Rate of Change (Rated V_R , $T_J = 25^{\circ}C$)	dv/dt	10,000	V/µs

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Min Pad	1 Inch Pad	Unit
Thermal Resistance, Junction-to-Lead (Note 1) Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JL} \ R_{ heta JA}$	22 150	15 81	°C/W

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 2)	V _F	T _J = 25°C	T _J = 100°C	V
$(I_F = 0.1 \text{ A})$ $(I_F = 1.0 \text{ A})$ $(I_F = 2.0 \text{ A})$		0.405 0.480 0.500	0.275 0.355 0.385	
Maximum Instantaneous Reverse Current		T _J = 25°C	T _J = 100°C	μΑ
(V _R = 5.0 V) (V _R = 10 V)		15 50	200 500	

1. Mounted on a 3" square FR4 PC Board with min. pads or 1" square copper heat spreader. 2. Pulse Test: Pulse Width \leq 250 µs, Duty Cycle \leq 2%.

MBRA210ET3

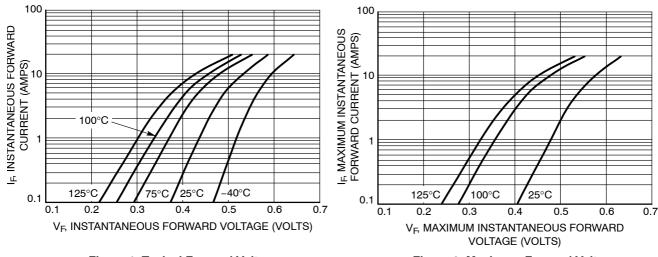
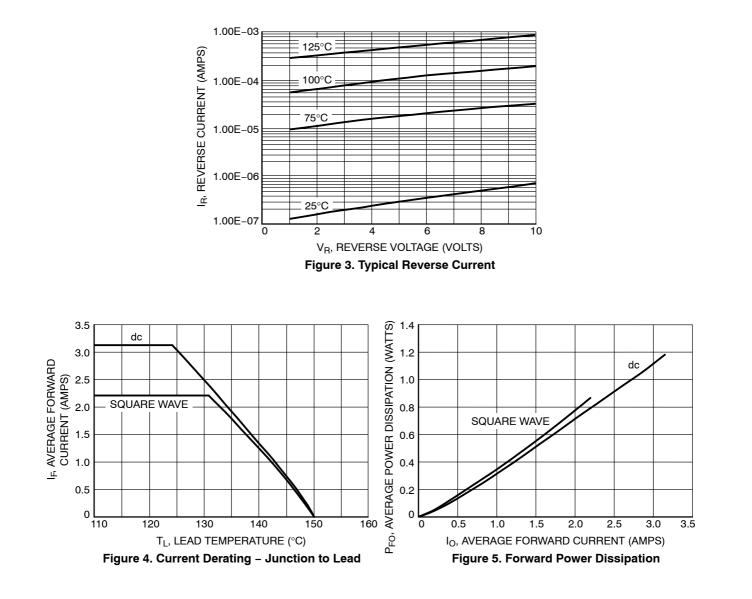
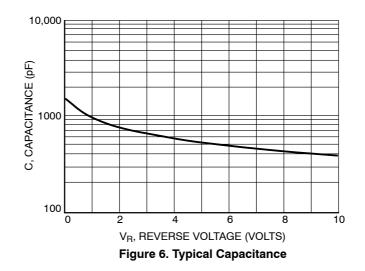


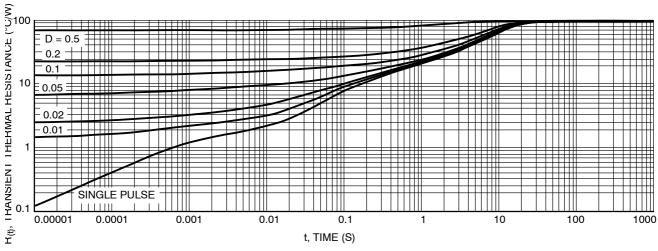


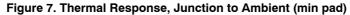
Figure 2. Maximum Forward Voltage



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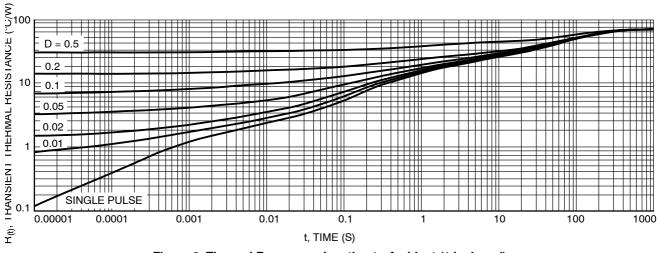


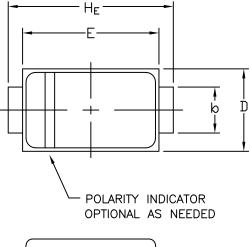
Figure 8. Thermal Response, Junction to Ambient (1 inch pad)

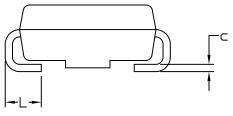
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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STYLE 1 STYLE 2 SCALE 1:1

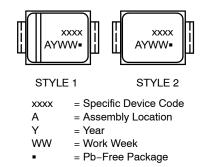




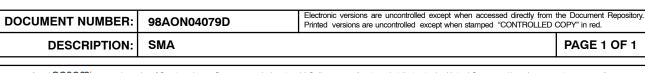


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GENERIC **MARKING DIAGRAM***



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



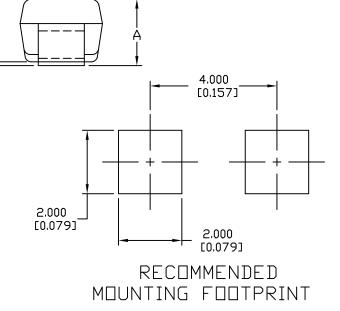
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- DIMENSION & SHALL BE MEASURED WITHIN DIMENSION L. З.

	MILLIMETERS			INCHES		
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
A	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.20	0.002	0.004	0.008
Ø	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060

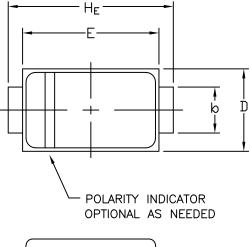


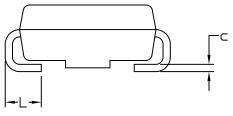
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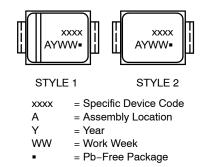




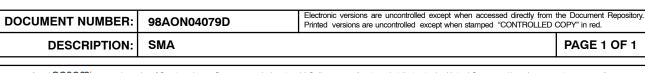


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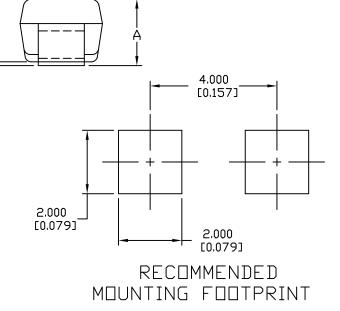
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